

Standard Recovery Diodes, (Stud Version), 400 A



FΕ	ΑТ	ſυ	R	ES
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- Wide current range
- High surge current capabilities





- Standard JEDEC® types
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- High power drives

PRIMARY CHARACTERISTICS				
I _{F(AV)}	400 A			
Package	DO-9 (DO-205AB)			
Circuit configuration	Single			

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
1		400	Α		
I _{F(AV)}	T _C	120	°C		
I _{F(RMS)}		630	Α		
1	50 Hz	8250	۸		
IFSM	60 Hz	8640	A		
l ² t	50 Hz	340	kA ² s		
	60 Hz	311	KA-S		
V _{RRM}	Range	800 to 1600	V		
TJ		-40 to +200	°C		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA		
	80	800	900			
VS-400U(R)	120	1200	1300	15		
	160	1600	1700			



FORWARD CONDUCTION						
PARAMETER	SYMBOL		TEST COND	DITIONS	VALUES	UNITS
Maximum average forward current	le	180° conduct	ion, half sine wa	VΑ	400 120	А
at case temperature	I _{F(AV)}	100 Conduct	ion, nan sine wa	ve		°C
Maximum RMS forward current	I _{F(RMS)}	DC at 110 °C	case temperatu	re	630	Α
		t = 10 ms	No voltage	Sinusoidal half wave, initial $T_J = T_J$ maximum	8250	A kA ² s
Maximum peak, one cycle forward,		t = 8.3 ms	reapplied		8640	
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM} reapplied		6940	
		t = 8.3 ms			7270	
	l ² t	t = 10 ms	No voltage reapplied		340	
Marrian and 124 for a function		t = 8.3 ms			311	
Maximum I ² t for fusing		t = 10 ms	100 % V _{RRM} reapplied		241	
		t = 8.3 ms			220	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied		3400	kA²√s	
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), $T_J = T_J$ maximum		0.77	V	
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		0.85	V	
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		0.49	mΩ	
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$ 0.49		11152		
Maximum forward voltage drop	V_{FM}	$I_{pk} = 1500 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sinusoidal wave}$		1.62	V	

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating and storage temperature range	T _J , T _{Stg}		-40 to 200	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.15	K/W
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.04	FV/VV
Maximum allowed mounting torque ± 10 %		Not lubricated threads	27	N⋅m
Approximate weight			250	g
Case style		See dimensions - link at the end of datasheet DO-9 (DO-205AB)		-205AB)

△R _{thJC} CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS		
180°	0.020	0.013				
120°	0.023	0.023				
90°	0.029	0.031	$T_J = T_J$ maximum	K/W		
60°	0.042	0.044				
30°	0.073	0.074				

Note

The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC



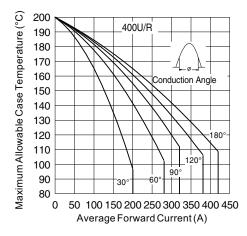


Fig. 1 - Current Ratings Characteristics

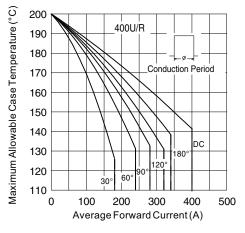


Fig. 2 - Current Ratings Characteristics

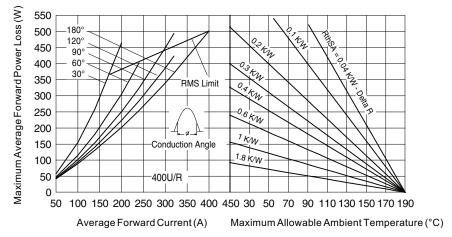


Fig. 3 - Forward Power Loss Characteristics

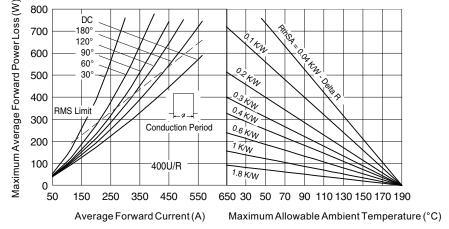


Fig. 4 - Forward Power Loss Characteristics

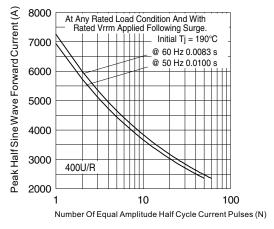


Fig. 5 - Maximum Non-Repetitive Surge Current

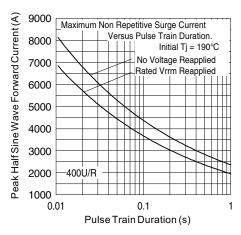


Fig. 6 - Maximum Non-Repetitive Surge Current

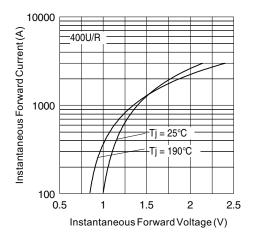


Fig. 7 - Forward Voltage Drop Characteristics

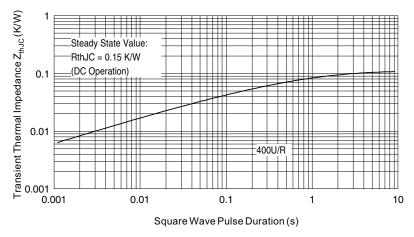
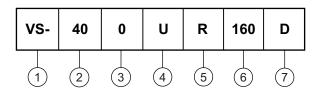


Fig. 8 - Thermal Impedance Z_{thJC} Characteristic



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - 40 = essential part number

- 0 = standard recovery device

- U = stud normal polarity (cathode to stud)

None = stud normal polarity (cathode to stud)

• R = stud reverse polarity (anode to stud)

Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

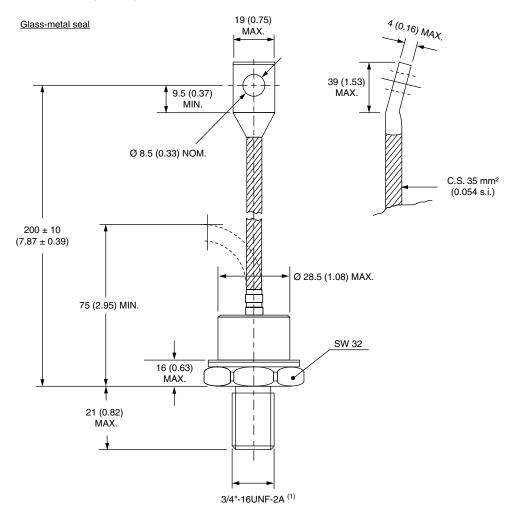
7 - Diffused diode

LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95339	



DO-205AB (DO-9) for 400U(R) Series

DIMENSIONS in millimeters (inches)



Note

• For metric device: M16 x 1.5 contact factory

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